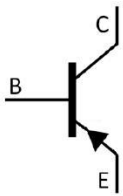


TO-92 PNP Silicon PNP transistor in a TO-92 Plastic Package.

High current, Low voltage.

500mA

General purpose amplifier and switch requiring collector currents up to 500 mA.



PIN1 Collector PIN 2 Base PIN 3 Emitter

See Marking Instructions.

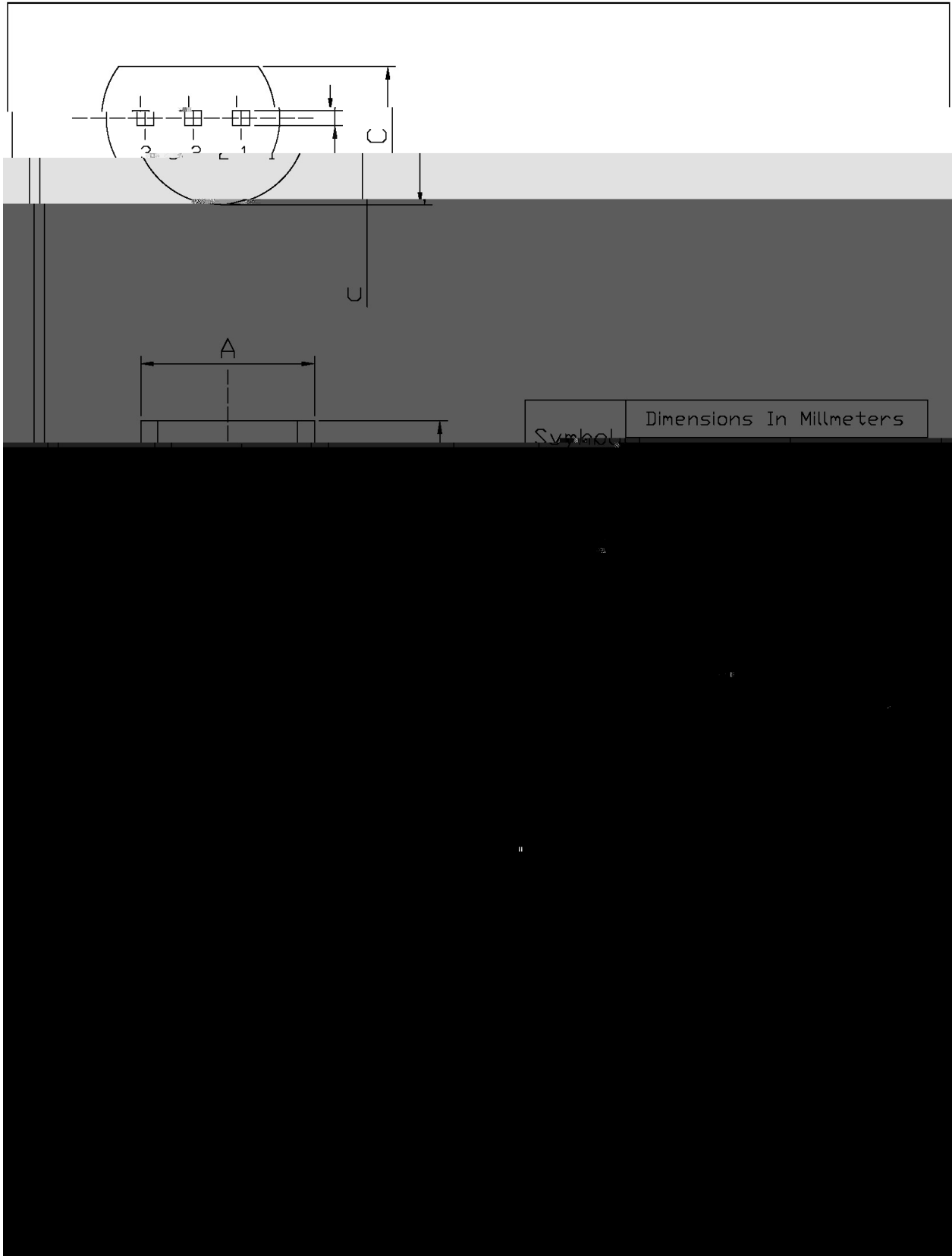
Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-40	V
Collector to Emitter Voltage	V_{CEO}	-40	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous	I_C	-600	mA
Collector Power Dissipation	P_C	625	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	/W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

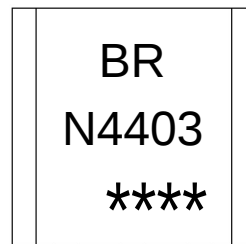
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Base Breakdown Voltage	V_{CBO}	$I_C = -0.1mA$ $I_E = 0$	-40			V
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C = -1.0mA$ $I_B = 0$	-40			V
Emitter to Base Breakdown Voltage	V_{EBO}	$I_E = -0.1mA$ $I_C = 0$	-5.0			V
Collector Cut-Off Current	I_{CBO}	$V_{CB} = -40V$ $I_E = 0$			-50	nA



T0-92

Unit: mm





BR

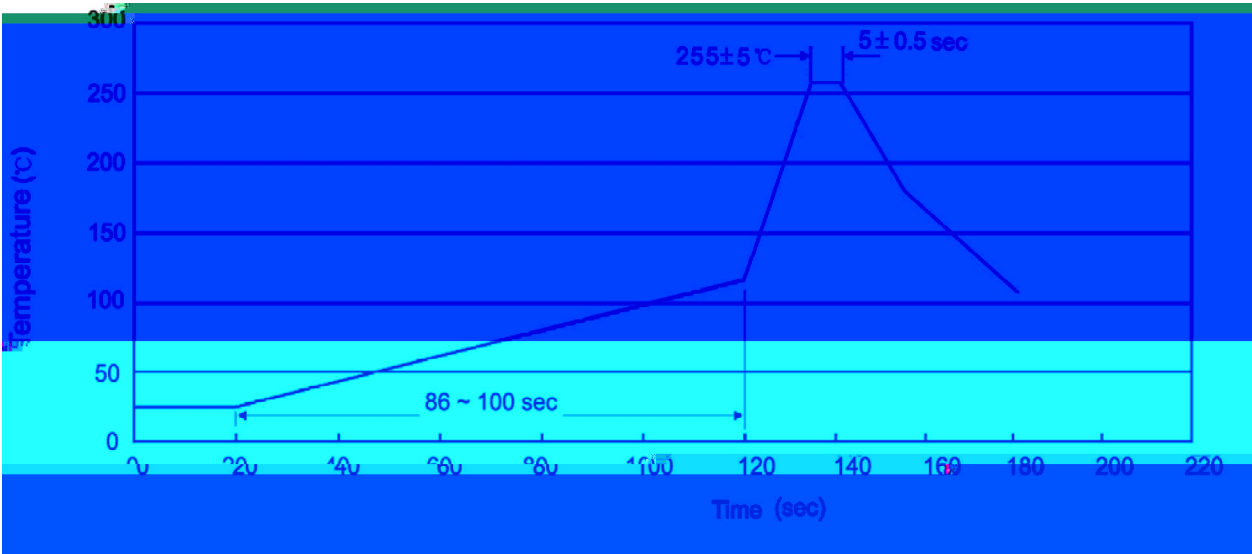
N4403

Note:

BR: Company Code.

N4403: Product Type.

****: Lot No. Code, code change with Lot No.



- Note:

1

25 150

60 90sec;

1.Preheating:25~150 , Time:60~90sec.

2

255±5

5±0.5sec;

2.Peak Temp.:255±5 , Duration:5±0.5sec.

3

2 10 /sec.

3. Cooling Speed: 2~10 /sec.

270±5

10±1 sec.

Temp.:270±5

Time:10±1 sec

/ BULK

Packag1 0 (T)TD-0.-2 :74TT4 1 T337 Tm0 g g g g8/TT9 1 Tf15.0514 0 Tagin-60 Tcn-60 T50a78j03 004 Tc165651042 Tw Tc[/)2280 5df05116d0ef